**ADVANCE INFORMATION** 

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

## TC74VCX16721FT

### LOW-VOLTAGE 20-BIT D-TYPE FLIP-FLOP WITH 3.6V TOLERANT INPUTS AND OUTPUTS

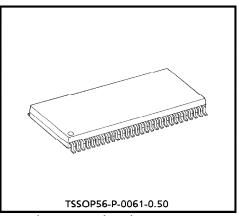
The TC74VCX16721FT is a high performance CMOS 20-bit D-TYPE FLIP-FLOP. Designed for use in 1.8, 2.5 or 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

It is also designed with over voltage tolerant inputs and outputs up to 3.6V.

The TC74VCX16721FT is edge-triggered D-type flip-flop with qualified clock storage. On the positive transition of the clock (CK) input, the device provides true data at the Q outputs if the clock-enable (CKEN) input is low. If CKEN is high, no data is stored.

When the  $\overline{OE}$  input is high, the outputs are in a high impedance state. This device is designed to be used with 3 - state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.25g (Typ.)

### **FEATURES**

RELIMINARY Low Voltage Operation

High Speed Operation :  $t_{pd} = TBD \text{ (max.)}$  at  $V_{CC} = 3.0 \sim 3.6 \text{V}$ 

:  $t_{pd} = TBD \text{ (max.)} \text{ at } V_{CC} = 2.3 \sim 2.7 \text{V}$ 

:  $t_{pd} = TBD (max.)$  at  $V_{CC} = 1.8V$ 

3.6V Tolerant inputs and outputs.

Output Current :  $I_{OH}/I_{OL} = \pm 24mA$  (min.) at  $V_{CC} = 3.0V$ 

:  $I_{OH}/I_{OL} = \pm 18mA \text{ (min.)}$  at  $V_{CC} = 2.3V$ 

:  $I_{OH}/I_{OL} = \pm 6mA \text{ (min.)}$  at  $V_{CC} = 1.8V$ 

Latch-up Performance : ±300mA

**ESD Performance** : Human Body Model > ±2000V

: Machine Model > ±200V

: TSSOP **Package** 

(Thin Shrink Small Outline Package)

Power Down Protection is provided on all inputs and outputs.

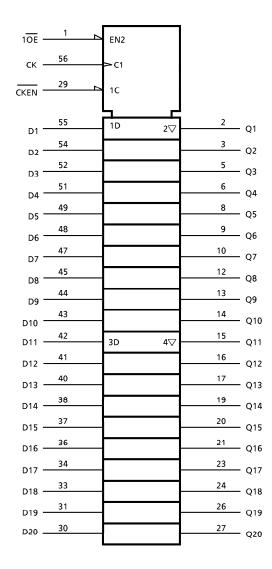
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### **PIN ASSIGNMENT**

#### 56 CK OE 55 D1 Q1 Q2 54 D2 GND 53 GND Q3 52 D3 Q4 51 D4 V<sub>CC</sub> 50 V<sub>CC</sub> 49 D5 Q5 Q6 48 D6 47 D7 Q7 GND 11 46 GND Q8 12 45 D8 Q9 13 44 D9 Q10 14 43 D10 Q11 15 42 D11 Q12 16 41 D12 Q13 17 40 D13 GND 18 39 GND 38 D14 Q14 19 37 D15 Q15 20 36 D16 Q16 21 35 V<sub>CC</sub> V<sub>CC</sub> Q17 23 34 D17 Q18 24 33 D18 GND 32 GND Q19 31 D19 Q20 30 D20 NC CKEN 28 29

### **SYMBOL**



(TOP VIEW)

## **PRELIMINARY**

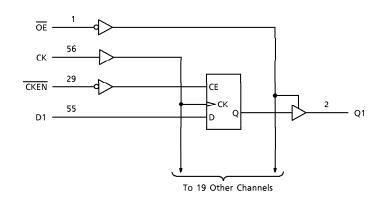
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### TRUTH TABLE (each flip flop)

	INP	UTS	OUTPUTS	
ŌĒ	CKEN	CK	D	Q
L	Н	Х	Х	Q0
L	L		Н	Н
L	L		L	L
L	L	7_	Х	Q0
Н	Х	Х	Х	Z

### SYSTEM DIAGRAM



# **PRELIMINARY**

### **MAXIMUM RATINGS**

PARAMETER	SYMBOL	RATING	UNIT			
Power Supply Voltage	Vcc	- 0.5~4.6	V			
DC Input Voltage	VIN	-0.5~4.6	V			
DC Output Valtage	V	−0.5~4.6 (Note 1)	V			
DC Output Voltage	Vout	-0.5~V <sub>CC</sub> + 0.5 (Note 2)				
Input Diode Current	ΙΚ	<b>–</b> 50	mA			
Output Diode Current	<sup>I</sup> ок	± 50 (Note 3)	mA			
DC Output Current	IOUT	± 50	mA			
Power Dissipation	PD	400	mW			
DC V <sub>CC</sub> / Ground Current Per Supply Pin	ICC / IGND	± 100	mA			
Storage Temperature	T <sub>stg</sub>	<b>-65∼150</b>	°C			

- (Note 1) Off-State
- (Note 2) High or Low State.  $I_{\mbox{OUT}}$  absolute maximum rating must be observed.
- (Note 3) VOUT < GND, VOUT > VCC